

# DIODE/THYRISTOR POWER MODULES

PHASE CONTROL, FAST, FAST SWITCHING  
(up to 1250 A / 4400 V)




## Features:

- High load cycle resistance (more as 100000 cycles,  $\Delta T = 100^{\circ}\text{C}$ ), safe operation by commutation of currents up to 1600 A in heavy operation conditions
- Pressure contact design
- Different circuits:
  - Single device (diode, thyristor, optothyristor, triac);
  - Two devices in parallel;
  - Two devices in series or in opposite directions (with common anode or cathode);
  - Two parallel devices in opposite directions;
  - Asymmetric thyristor with opposite diode and other
- Base plate width 20, 34, 50, 60, 70, 77, 90 mm


## Applications:

- Rectifier bridges
- AC controllers
- Soft starters for AC motors
- DC motors control
- Input rectifiers in invertors
- Temperature control (for example, in furnaces and chemical processes)
- AC motors ccontrol
- DC current interrupters
- Inductive heating
- Uninterruptible supplies
- Welding

## RECTIFIER DIODE MODULES

Type	$V_{RRM}$	$I_{F(AV)}$ ( $T_C$ : °C)	$I_{FSM}$ 10ms	$V_{TO}$	$r_T$	$R_{th(j-c)}$	$T_{VJM}$	$V_{isol}$	Case							
	V	A	kA	V	mΩ	°C/W	°C	V								
MDD-40 MDDA-40 MDDC-40	400-1800	40(100)	1.2	1.0	3.80	0.680	140	2500	 MTD1 w =200g							
MDD-63 MDDA-63 MDDC-63										400-1800	63(100)	1.6	0.95	2.70	0.460	140
MDD-80 MDDA-80 MDDC-80																
M2D-160 M2DA-160 M2DC-160	2400-3200	180(85)	5.5	0.85	0.85	0.18	125									
M2D-200 M2DA-200 M2DC-200								1200-2200		211(85)	7.0	0.77	0.54	0.18	125	
MDD-125 MDDA-125 MDDC-125																400-1600
MDD-160 MDDA-160 MDDC-160	400-1600	160(89)	6.0	0.90	0.55	0.18	125									
M2D-250 M2DA-250								2600-3200		286(85)	9.0	0.85	0.38	0.125	125	
MDD-320 MDDA-320																1200-2400
MDD-200 MDDA-200	400-1600	200(89)	7.0	0.9	0.60	0.13	125									
MDDA-250 MDD-250								400-1600	250(85)	11	0.9	0.56	0.12	125		
M1D1-400 M1D1-500															3400-4000	530(85)
M1D1-630	1200-2200	830(85)	19	0.77	0.18	0.068	150									
M1D-400 M1D-500								1900-2800	600(85)	18	0.90	0.30	0.068	140		
M1D-630															1300-2600	730(85)
M1D-630	200-1200	850(85)	24	0.80	0.15	0.068	150									
M2D1-400 M2D1A-400								3400-4000	530(85)	12	0.9	0.46	0.068	140		
M2D1-500 M2D1A-500															2400-3200	705(85)
M2D1A-630 M2D1-630	1200-2200	830(85)	19	0.77	0.18	0.068	150									
M2DA-400 M2D-400								1900-2800	600(85)	18	0.90	0.30	0.068	140		
M2DA-500 M2D-500															1300-2600	730(85)
M2DA-630 M2D-630	200-1200	850(85)	24	0.80	0.15	0.068	150									
M1D2-630 M1D-800								2900-4400	920(85)	20	1.00	0.30	0.042	150		
M1D-1000															1900-2800	1110(85)
M1D-1000	400-1800	1260(85)	32	0.85	0.12	0.042	150									

## RECTIFIER DIODE MODULES

Type	$V_{RRM}$ V	$I_{F(AV)}$ ( $T_{Cj}, ^\circ C$ ) A	$I_{FSM}$ 10ms kA	$V_{TO}$ V	$r_T$ m $\Omega$	$R_{th(j-c)}$ $^\circ C/W$	$T_{VJM}$ $^\circ C$	$V_{isol}$ V	Case
M2D2-630 M2D2A-630 M2D2C-630	2900-4400	760(100)	20	1.00	0.30	0.042	150	3500	 MTD7 w=4000g
M2D2-800 M2D2A-800 M2D2C-800	1900-2800	910(100)	28	0.90	0.18	0.042	150	3000	
M2D2-1000 M2D2A-1000 M2D2C-1000	400-1800	1030(100)	32	0.85	0.12	0.042	150	3000	

## AVALANCHE DIODE MODULES WITH HIGH INSULATION VOLTAGE

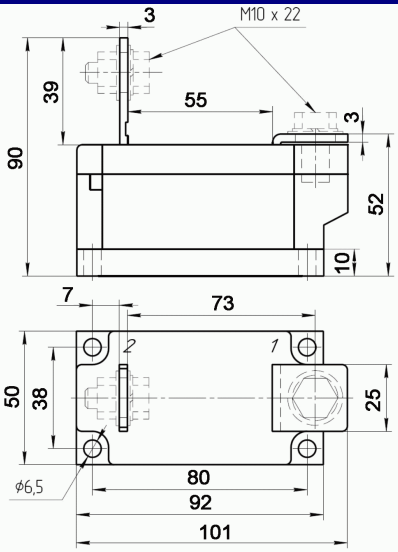
### Features:


- Standard case
- Insulation voltage up to 9.5 kV between main terminals and base plate
- Guaranteed power dissipation by avalanche breakdown


### Applications:

- Railway converters

Type	$V_{RRM}$ V	$I_{F(AV)}$ ( $T_{Cj}, ^\circ C$ ) A	$I_{FSM}$ 10ms kA	$V_{TO}$ V	$r_T$ m $\Omega$	$P_{RSM}$ kW	$R_{th(j-c)}$ $^\circ C/W$	$T_{VJM}$ $^\circ C$	$V_{isol}$ V	Case
M1DL-400-40	2800-4000	400(85)	12	1.0	0.77	16	0.09	150	9500	MTD4-1














MTD4-1

## PHASE CONTROL THYRISTOR MODULES

Type	$V_{DRM}$ , $V_{RRM}$ V	$I_{T(AV)}$ ( $T_C$ , °C) A	$I_{TSM}$ 10ms kA	$V_{T(TO)}$ V	$r_T$ mΩ	$(di_T/dt)_{cr}$ A/μs	$(dv_D/dt)_{cr}$ V/μs	$t_q$ (typ) μs	$R_{th(j-c)}$ °C/W	$T_{VJM}$ °C	$V_{isol}$ V	Case										
MTT-40	400-1600	40(85)	0.8	1.00	3.80	200	500-1000	100	0.680	125	2500	 MTD1 w =200g										
MTTA-40																						
MTTC-40																						
MTT-63	400-1600	63(85)	1.2	0.95	3.0	200	500-1000	125	0.460	125	2500											
MTTA-63																						
MTTC-63																						
MTT-80	400-1200	80(75)	1.6	0.90	2.00	200	500-1000	160	0.450	125	2500											
MTTA-80																						
MTTC-80																						
M2T-100	2600-3200	116(85)	3.5	1.15	2.6	200	1000	320	0.180	125	2500	 MTD2 w =500g										
M2TA-100																						
M2TC-100																						
M2T-125	1800-2400	140(85)	4.0	1.05	1.5	200	1000	250	0.180	125	2500											
M2TA-125																						
M2TC-125																						
M2T-200	400-1200	218(85)	5.5	0.83	0.58	200	1000	125	0.180	130	2500											
M2TA-200																						
M2TC-200																						
MTT-100	400-1600	100(85)	2.5	1.15	2.40	320	1000	160	0.220	125	2500											
MTTA-100																						
MTTC-100																						
MTT-125	400-1600	125(85)	3.0	1.10	1.80	320	1000	200	0.190	125	2500											
MTTA-125																						
MTTC-125																						
MTT-160	400-1600	160(85)	4.5	1.00	1.05	320	1000	200	0.180	125	2500											
MTTA-160																						
MTTC-160																						
MTT1-200	600-1400	200(73)	5.0	0.95	1.25	500	1000	125	0.180	130	2500											
MTT1A-200																						
MTT1C-200																						
M2T1-160	2600-3200	175(85)	5.0	1.15	1.50	200	1000	320	0.125	125	3000	 MTD3 w =800g										
M2T1A-160																						
M2T1-200													1800-2400	210(85)	7.0	1.05	0.85	200	1000	250	0.125	125
M2T1A-200																						
M2T-250	1200-1800	280(85)	8.0	0.95	0.5	200	1000	160	0.125	130	3000											
M2TA-250																						
M2T1-320													600-1200	375(85)	10	0.85	0.35	200	1000	125	0.125	140
M2T1A-320																						
MTT2-160	400-1600	170(85)	5.4	1.15	1.00	320	1000	160	0.150	125	3000											
MTT2A-160																						
MTT-200													400-1600	200(85)	6.0	1.05	0.95	320	1000	160	0.130	125
MTTA-200																						
MTT-250	400-1600	250(85)	7.0	1.05	0.53	320	1000	160	0.120	125	3000											
MTTA-250																						
M1T-250												3400-4000	300(85)	6.0	1.2	1.0	200	1000	400	0.068	125	3000
M1T-320	2600-3200	357(85)	8.0	1.00	0.735	200	1000	320	0.068	125	3000											
M1T1-400																						
M1T1-500												800-1800	500(85)	13	0.95	0.3	200	1000	160	0.068	130	3000
M1T-400	1300-1800	460(85)	13	0.92	0.32	200	1000	160	0.068	125	3000											
M1T-500																						
M1T-630												400-1200	660(85)	17	0.81	0.25	200	1000	125	0.068	140	3000

## PHASE CONTROL THYRISTOR MODULES

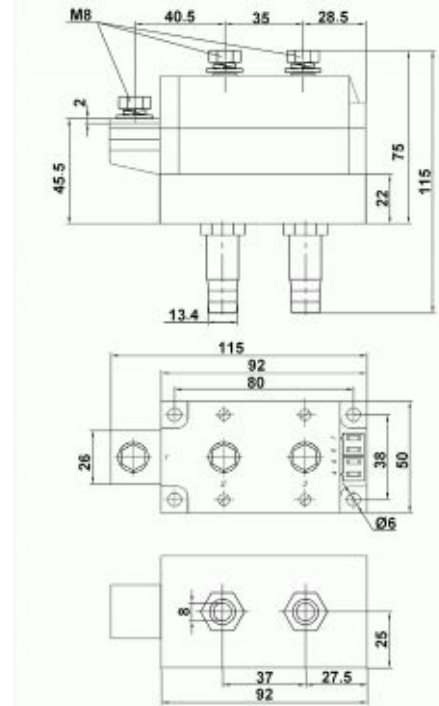
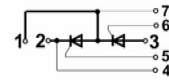
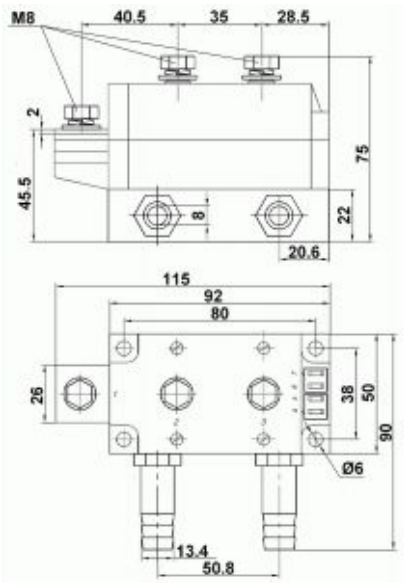
Type	$V_{DRM},$ $V_{RRM}$ V	$I_{T(AV)}$ ( $T_C, ^\circ C$ ) A	$I_{TSM}$ 10ms kA	$V_{T(TO)}$ V	$r_T$ m $\Omega$	$(di_T/dt)_{cr}$ A/ $\mu s$	$(dv_D/dt)_{cr}$ V/ $\mu s$	$t_q$ (typ) $\mu s$	$R_{th(j-c)}$ $^\circ C/W$	$T_{VJM}$ $^\circ C$	$V_{isol}$ V	Case		
M2T1-250 M2T1A-250	3000-4000	300(85)	6.0	1.2	1.0	200	1000	400	0.068	125	3000	 MTD5 w =1500g		
M2T-320 M2TA-320	2600-3200	357(85)	8.0	1.00	0.735	200	1000	320	0.068	125	3000			
M2T1-400 M2T1A-400	1800-2400	407(85)	9.0	1.02	0.42	200	1000	250	0.068	125	3000			
M2T-400 M2TA-400	1300-1800	460(85)	13	0.92	0.32	200	1000	200	0.068	125	3000			
M2T1-500 M2T1A-500	800-1800	500(85)	13	0.95	0.3	200	1000	200	0.068	130	3000			
M2T-500 M2TA-500	200-1200	545(85)	14	0.85	0.27	200	1000	125	0.068	130	3000			
M2T-630 M2TA-630	400-1200	660(85)	17	0.81	0.25	200	1000	125	0.068	140	3000			
M1T2-400 M1T2-500 M1T2-630	3600-4000 2900-3400 1900-2800	492(85) 570(85) 660(80)	15 18 20	1.18 1.10 1.05	0.62 0.40 0.35	200 200 200	1000 1000 1000	400 320 320	0.042 0.042 0.042	125 125 125	2500 2500 2500		 MTD6 w =2300g	
M1T-800 M1T-1000 M1T1-1250	1300-1800 400-1200 400-800	840(80) 1020(85) 1250(85)	23 28 30	1.00 0.90 0.83	0.20 0.15 0.10	200 200 200	1000 1000 1000	200 160 100	0.042 0.042 0.042	130 140 150	2500 2500 2500			
M2T2-400 M2T2A-400 M2T2C-400	3600-4000	492(85)	15	1.18	0.62	200	1000	400	0.042	125	3500			 MTD7 w =4000g
M2T2-500 M2T2A-500 M2T2C-500	2900-3400	570(85)	18	1.10	0.40	200	1000	320	0.042	125	3500			
M2T2-630 M2T2A-630 M2T2C-630	1900-2800	630(85)	20	1.02	0.32	200	1000	320	0.042	125	3000			
M2T2-800 M2T2A-800 M2T2C-800	1300-1800	820(85)	23	0.93	0.17	200	1000	200	0.042	130	3000			
M2T2-1000 M2T2A-1000 M2T2C-1000	400-1200	1035(85)	28	0.90	0.15	200	1000	160	0.042	140	3000			
M2T2-1250 M2T2A-1250 M2T2C-1250	400-800	1250(85)	30	0.83	0.10	200	1000	125	0.042	150	3000			
M1T-1600 M1T-1250 M1T2-1000	200-1200 1200-1800 1800-2400	1610(85) 1340(85) 1110(85)	60* 49 42	0.85 0.90 0.90	0.064 0.07 0.14	200 200 200	1000 1000 1000	200 250 320	0.028 0.028 0.028	135 130 125	3000 3000 3000	 MTD8 w* =4300g		

## THYRISTOR MODULES WITH INTERNAL LIQUID COOLING

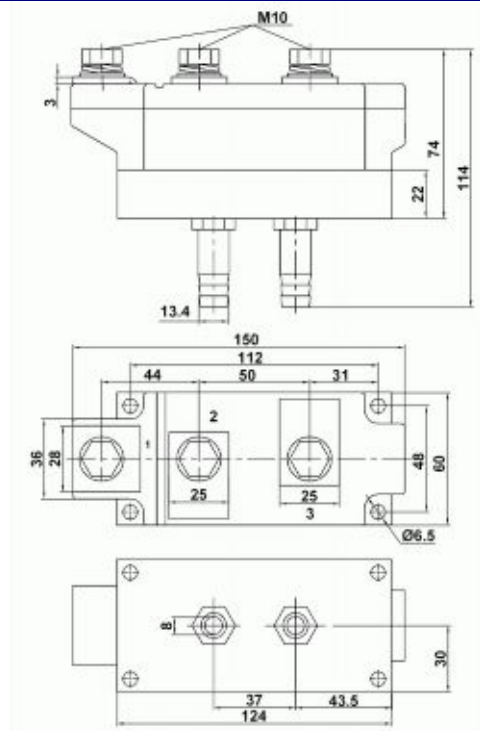
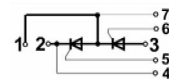
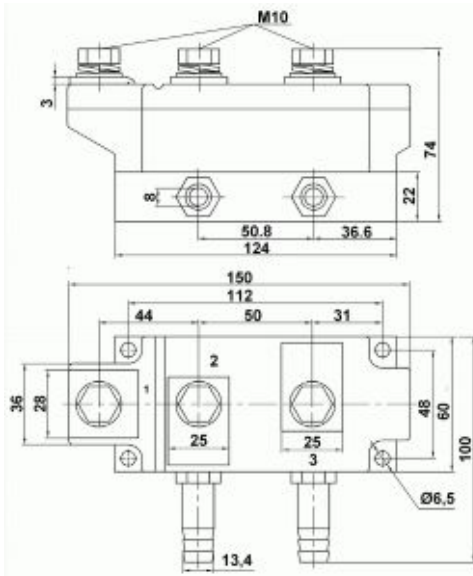
Type	$V_{DRM}$ , $V_{RRM}$	$I_{RMS}$ ( $T_w$ , °C)	$I_{TSM}$ 10ms	$V_{T(TO)}$	$r_T$	$(di_T/dt)_{cr}$	$(dv_D/dt)_{cr}$	$t_q$ (typ)	$R_{thjw}$	$T_{VJM}$	$V_{isol}$	Case
	V	A	kA	V	mΩ	A/μs	V/μs	μs	°C/W	°C	V	
M2T-800-...-OB	1200-1800	825(25) 735(40)	8	0.95	0.5	200	1600	160	0.2	130	3000	MTD w =1300g
M2T-1550-...-OB	400-1200	1573(85) 1418(40)	17	0.81	0.25	200	1000	160	0.13	140	3000	MTD w =1300g

Module with side openings for cooling liquid

Module with bottom openings for cooling liquid






M2T-800-...-OB



M2T-1550-...-OB

## PHASE CONTROL THYRISTOR-DIODE AND DIODE-THYRISTOR MODULES

Type	$V_{DRM}$ , $V_{RRM}$	$I_{T(AV)}$ ( $T_C$ , °C)	$I_{TSM}$ 10ms	$V_{T(TO)}$	$r_T$	$(di_T/dt)_{cr}$	$(dv_D/dt)_{cr}$	$t_q$ (typ)	$R_{th(j-c)}$	$T_{VJM}$	$V_{isol}$	Case	
	V	A	kA	V	mΩ	A/μs	V/μs	μs	°C/W	°C	V		
MTD-40, MDT-40 MTDA-40, MDTA-40 MTDC-40, MDTC-40	400-1600	40(85)	0.8	1.0	3.8	200	500-1000	100	0.680	125	2500	 MTD1 w =200g	
MTD-63, MDT-63 MTDA-63, MDTA-63 MTDC-63, MDTC-63	400-1600	63(85)	1.2	0.94	2.8	200	500-1000	125	0.460	125	2500		
MTD-80, MDT-80 MTDA-80, MDTA-80 MTDC-80, MDTC-80	400-1600	80(75)	1.6	0.9	2.0	200	500-1000	160	0.450	125	2500		
MTD1-100, MDT1-100 MTD1A-100, MDT1A-100 MTD1C-100, MDT1C-100	2600-3200	116(85)	3.5	1.15	2.6	200	1000	320	0.180	125	2500		 MTD2 w =500g
MTD1-125, MDT1-125 MTD1A-125, MDT1A-125 MTD1C-125, MDT1C-125	1800-2400	140(85)	4.0	1.05	1.5	200	1000	200	0.180	125	2500		
MTD1-160, MDT1-160 MTD1A-160, MDT1A-160 MTD1C-160, MDT1C-160	400-1600	180 (85)	5.0	0.9	0.75	200	1000	160	0.180	125	2500		
MTD1-200, MDT1-200 MTD1A-200, MDT1A-200 MTD1C-200, MDT1C-200	400-1200	218(85)	5.5	0.83	0.58	200	1000	125	0.180	130	2500		
MTD-100, MDT-100 MTDA-100, MDTA-100 MTDK-100, MDTK-100	400-1600	100(85)	2.5	1.15	2.40	200	1000	160	0.220	125	2500		
MTD-125, MDT-125 MTDA-125, MDTA-125 MTDC-125, MDTC-125	400-1600	125(85)	3.0	1.10	1.80	200	1000	200	0.190	125	2500		
MTD-160, MDT-160 MTDA-160, MDTA-160 MTDC-160, MDTC-160	400-1600	160(85)	4.5	1.00	1.05	200	1000	200	0.180	125	2500		
MTD2-160, MDT2-160 MTD2A-160, MDT2A-160	2600-3200	172(85)	5.0	1.15	1.50	200	1000	320	0.13	125	3000	 MTD3 w =800g	
MTD2-200, MDT2-200 MTD2A-200, MDT2A-200	1800-2400	207(85)	7.0	1.05	0.85	200	1000	250	0.13	125	3000		
MTD1-250, MDT1-250 MTD1A-250, MDT1A-250	1200-1800	269(85)	8.0	0.95	0.5	200	1000	160	0.13	130	3000		
MTD1-320, MDT1-320 MTD1A-320, MDT1A-320	600-1200	360(85)	10	0.85	0.35	200	1000	125	0.13	140	3000		
MTD-200, MDT-200 MTDA-200, MDTA-200	400-1600	200(85)	6.0	1.05	0.95	200	1000	160	0.13	125	3000		
MTD-250, MDT-250 MTDA-250, MDTA-250	400-1600	250(85)	7.0	1.05	0.53	320	1000	160	0.12	125	3000		







## PHASE CONTROL THYRISTOR-DIODE AND DIODE-THYRISTOR MODULES

Type	$V_{DRM}$ $V_{RRM}$	$I_{T(AV)}$ ( $T_C$ °C)	$I_{TSM}$ 10ms	$V_{T(To)}$	$r_T$	$(di_T/dt)_{cr}$	$(dv_D/dt)_{cr}$	$t_q$ (typ)	$R_{th(j-c)}$	$T_{VJM}$	$V_{isol}$	Case	
	V	A	kA	V	mΩ	A/μs	V/μs	μs	°C/W	°C	V		
MTD2-250, MDT2-250 ----- MTD2A-250, MDT2A-250	3000-4000	300(85)	6.0	1.2	1.00	200	1000	400	0.068	125	3000	 MTD5 w =1500g	
MTD1-400, MDT1-400 ----- MTD1A-400, MDT1A-400	1800-2400	407(85)	9.0	1.02	0.42	200	1000	250	0.068	125	3000		
MTD1-500, MDT1-500 ----- MTD1A-500, MDT1A-500	800-1800	500(85)	13	0.95	0.30	200	1000	200	0.068	130	3000		
MTD-320, MDT-320 ----- MTDA-320, MDTA-320	2600-3200	357(85)	8.0	1.00	0.735	200	1000	320	0.068	125	3000		
MTD-400, MDT-400 ----- MTDA-400, MDTA-400	1300-1800	460(85)	13	0.92	0.32	200	1000	160	0.068	125	3000		
MTD-500, MDT-500 ----- MTDA-500, MDTA-500	200-1200	545(85)	14	0.85	0.27	200	1000	125	0.068	130	3000		
MTD-630, MDT-630 ----- MTDA-630, MDTA-630	200-1200	660(85)	15	0.81	0.25	200	1000	125	0.068	140	3000		
MTD2-400, MDT2-400 ----- MTD2A-400, MDT2A-400 ----- MTD2C-400, MDT2C-400	3600-4000	492(85)	15	1.18	0.62	200	1000	400	0.042	125	3500		 MTD7 w =4000g
MTD2-500, MDT2-500 ----- MTD2A-500, MDT2A-500 ----- MTD2C-500, MDT2C-500	2900-3400	570(85)	18	1.10	0.40	200	1000	320	0.042	125	3500		
MTD2-630, MDT2-630 ----- MTD2A-630, MDT2A-630 ----- MTD2C-630, MDT2C-630	1900-2800	660(80)	20	1.05	0.35	200	1000	320	0.042	125	3000		
MTD2-800, MDT2-800 ----- MTD2A-800, MDT2A-800 ----- MTD2C-800, MDT2C-800	1300-1800	840(80)	23	0.93	0.17	200	1000	200	0.043	130	3000		
MTD2-1000, MDT2-1000 ----- MTD2A-1000, MDT2A-1000 ----- MTD2C-1000, MDT2C-1000	400-1200	1020(85)	28	0.90	0.13	200	1000	160	0.043	140	3000		
MTD2-1250, MDT2-1250 ----- MTD2A-1250, MDT2A-1250 ----- MTD2C-1250, MDT2C-1250	400-800	1060(85)	30	0.85	0.11	200	1000	160	0.043	150	3000		





## FAST DIODE MODULES

Type	$V_{RRM}$	$I_{F(AV)}$ ( $T_C, ^\circ C$ )	$I_{FSM}$ 10ms	$V_{TO}$	$r_T$	$t_{rr}$	$R_{th(j-c)}$	$T_{VJM}$	$V_{isol}$	Case	
	V	A	kA	V	m $\Omega$	$\mu s$	$^\circ C/W$	$^\circ C$	V		
M2DF-40	400-1600	40(85)	1.6	1.4	5.0	0.50-1.00	0.46	140	2500	 MTD1 w =200g	
M2DF A-40											
M2DFC-40											
M2DF-63	400-1600	63(85)	1.8	1.2	4.0	0.63-1.00	0.46	140	2500		
M2DFA-63											
M2DFC-63											
M2DF-80	400-1400	80(75)	2.0	1.1	3.5	0.63-1.00	0.45	140	2500		
M2DFA-80											
M2DFC-80											
MDFDF-160	300-1400	160(85)	4.5	1.30	1.60	5	0.22	140	2500	 MTD2 w =500g	
MDFDFA-160											
MDFDFC-160											
MDFDF-400	400-1800	400(98)	10	0.95	0.4	1-5	0.12	140	3000	 MTD3 w =800g	
MDFDFA-400											
MDFDF1-400	800-2500	400(88)	10	1.05	0.7	1-5	0.12	140	3000		
MDFDF1A-400											
M1DF-250	1900-2800	450(85)	12	1.20	0.50	2.5-8	0.068	140	3000		 MTD4 w =900g
M1DF-320	1300-1800	490(85)	14	1.15	0.40	2.5-8	0.068	140	3000		
M1DF-400	200-1200	530(85)	16	1.10	0.30	2.5-8	0.068	140	3000		
M2DF-250	1900-2800	450(85)	12	1.20	0.50	2.5-8	0.068	140	3000	 MTD5 w =1500g	
M2DFA-250											
M2DF-320	1300-1800	490(85)	14	1.15	0.40	2.5-8	0.068	140	3000		
M2DFA-320											
M2DF-400	200-1200	530(85)	16	1.10	0.30	2.5-8	0.068	140	3000		
M2DFA-400											
M1DF-500	2900-4400	730(85)	16	1.20	0.50	2.5-8	0.042	150	3000	 MTD6 w =2300g	
M1DF-630	1900-2800	820(85)	20	1.15	0.35	2.5-8	0.042	150	3000		
M1DF-800	400-1800	930(85)	24	1.10	0.24	2.5-8	0.042	150	3000		
MDF1-800	1800-2600	800(90)	24	1.10	0.24	500 $\mu C$	0.042	150	3000		
M1DF-1000	2600	1100(90)	32	1.0	0.19	500 $\mu C$	0.030	140	3000	 MTD8 w* =4300g	

## FAST THYRISTOR MODULES

Type	$V_{DRM}$	$I_{T(AV)}$ ( $T_C$ , °C)	$I_{TSM}$ 10ms	$V_{T(TO)}$	$r_T$	$(di_T/dt)_{cr}$	$(dv_D/dt)_{cr}$	$t_q$ (typ)	$R_{th(j-c)}$	$T_{VJM}$	$V_{isol}$	Case																																	
	$V_{RRM}$ V												A	kA	V	mΩ	A/μs	V/μs	μs	°C/W	°C	V																							
M2TF-40 M2TFA-40 M2TFC-40	400-1600	40(85)	1.0	1.4	5.0	125	100-1000	25	0.46	125	2500	 MTD1 w =200g																																	
M2TF-63 M2TFA-63 M2TFC-63													400-1600	63(75)	1.1	1.2	4.0	125	100-1000	25	0.45	125	2500																						
MTFTF-100 MTFTFA-100 MTFTFC-100																								500-1000	100(85)	4	1.10	1.80	500	1000	40	0.220	125	2500	 MTD2 w =500g										
MTF-250	900-2800	315(85)	8	1.40	0.60	200	500-1000	63	0.068	125	3000	 MTD4 w =900g																																	
M1TF-400													1900-2800	315(85)	8	1.40	0.60	200	500-1000	63	0.068	125	3000													 MTD5 w =1500g									
M2TF-250 M2TFA-250	1300-1800	330(85)	9	1.35	0.50	200	500-1000	50	0.068	125	3000																																		
M2TF-320 M2TFA-320												200-1200												400(80)	10	1.30	0.35	200	500-1000	40	0.068	125	3000												
M2TF-400 M2TFA-400	2900-3400	470(85)	12	1.40	0.5	200	500-1000	125	0.042	125	3000		 MTD6 w =2300g																																
M1TF2-400												1900-2800		510(85)	14	1.35	0.4	200	500-1000	100	0.042	125	3000																						
M1TF-500																								1300-1800	550(85)	18	1.30	0.3	200	500-1000	80	0.042	125	3000											
M1TF2-500																																			600-1200	630(85)	20	1.20	0.2	200	500-1000	63	0.042	125	3000
M1TF-630																																													
M1TF-800	2200-2400	1020(70)	30	1.28	0.29	300	1000	120	0.030	130	3000	 MTD8 w* =4300g																																	
M1TF-1000																																													

## FAST THYRISTOR-DIODE AND DIODE-THYRISTOR MODULES

Type	$V_{DRM}$	$I_{T(AV)}$	$I_{TSM}$	$V_{T(TO)}$	$r_T$	$(di_T/dt)_{cr}$	$(dv_D/dt)_{cr}$	$t_q/t_{rr}$	$R_{th(j-c)}$	$T_{VJM}$	$V_{isol}$	Case	
	V	A	kA	V	m $\Omega$	A/ $\mu$ s	V/ $\mu$ s	$\mu$ s	$^{\circ}$ C/W	$^{\circ}$ C	V		
MTFDF-40, MDFTF-40 ----- MTFDFA-40, MDFTFA-40 ----- MTFDFC-40, MDFTFC-40 ----- MTFDF-63, MDFTF-63 ----- MTFDFA-63, MDFTFA-63 ----- MTFDFC-63, MDFTFC-63	400-1600	40(85)	1.0	1.4	5.0	125	100-1000	25/0.63	0.46	125	2500	 MTD1 w =200g	
MTFDF-100, MDFTF-100 ----- MTFDF-200, MDFTF-200	500-1000	100(85)	4.0	1.10	1.80	500	1000	40/-	0.210	125	2500		
MTFDF-250, MDFTF-250	600-1400	200(62)	4.0	1.15	1.50	500	500-1000	63/ 300 $\mu$ C	0.180	130	2500		 MTD2 w =500g
MTFDF-320, MDFTF-320	600-1400	250(81)	6.5	1.15	0.8	500	500-1000	63/ 300 $\mu$ C	0.180	130	3000		 MTD3 w =800g
MTFDF-400, MDFTF-400	1300-1800	330(85)	9.0	1.35	0.50	200	500-1000	50/ 2.5-8	0.068	130	3000		 MTD5 w =1500g

### NEW THYRISTOR-DIODE MODULE MTAADF-400-16 FOR INDUCTION HEATING CONVERTERS

**Features:**

- Short turn-off times of thyristors and reverse recovery times of diodes
- Low on-state losses
- High values of  $(di_T/dt)_{cr}$ ,  $(dv_D/dt)_{cr}$
- Internal insulation. Between terminals and baseplate.
- Precision pressure contacts provides high reliability by cycle loading operation

**Applications:**

- Frequency converters for power supplies of induction heating, surface hardening and metals melting equipment
- Optimized for operation frequency up to 4 kHz
- Module design makes it possible for converter designer to realize two alternative circuits: asymmetric thyristor and fast diode in opposite parallel or in series




Type	$V_{DRM}$	$V_{RRM}$	$I_{T(AV)}$	$I_{TSM}$	$V_{T(TO)}$	$r_T$	$(di_T/dt)_{cr}$	$(dv_D/dt)_{cr}$	$t_q/t_{rr}$	$R_{th(j-c)}$	$T_{VJM}$	$V_{isol}$	Case
	V	V	A	kA	V	m $\Omega$	A/ $\mu$ s	V/ $\mu$ s	$\mu$ s	$^{\circ}$ C/W	$^{\circ}$ C	V	
MTAADF-400	1200-1600	7 <sup>1)</sup> ----- 1200-1600 <sup>2)</sup>	400 (69)	7.0	1.80	0.53	1000	1000	12/1.5	0.060/ 0.030	125	3000	MTD5 w =1500g



<sup>1)</sup> for thyristor and diode in opposite parallel

<sup>2)</sup> for thyristor and diode in series

## FAST SWITCHING THYRISTOR MODULES

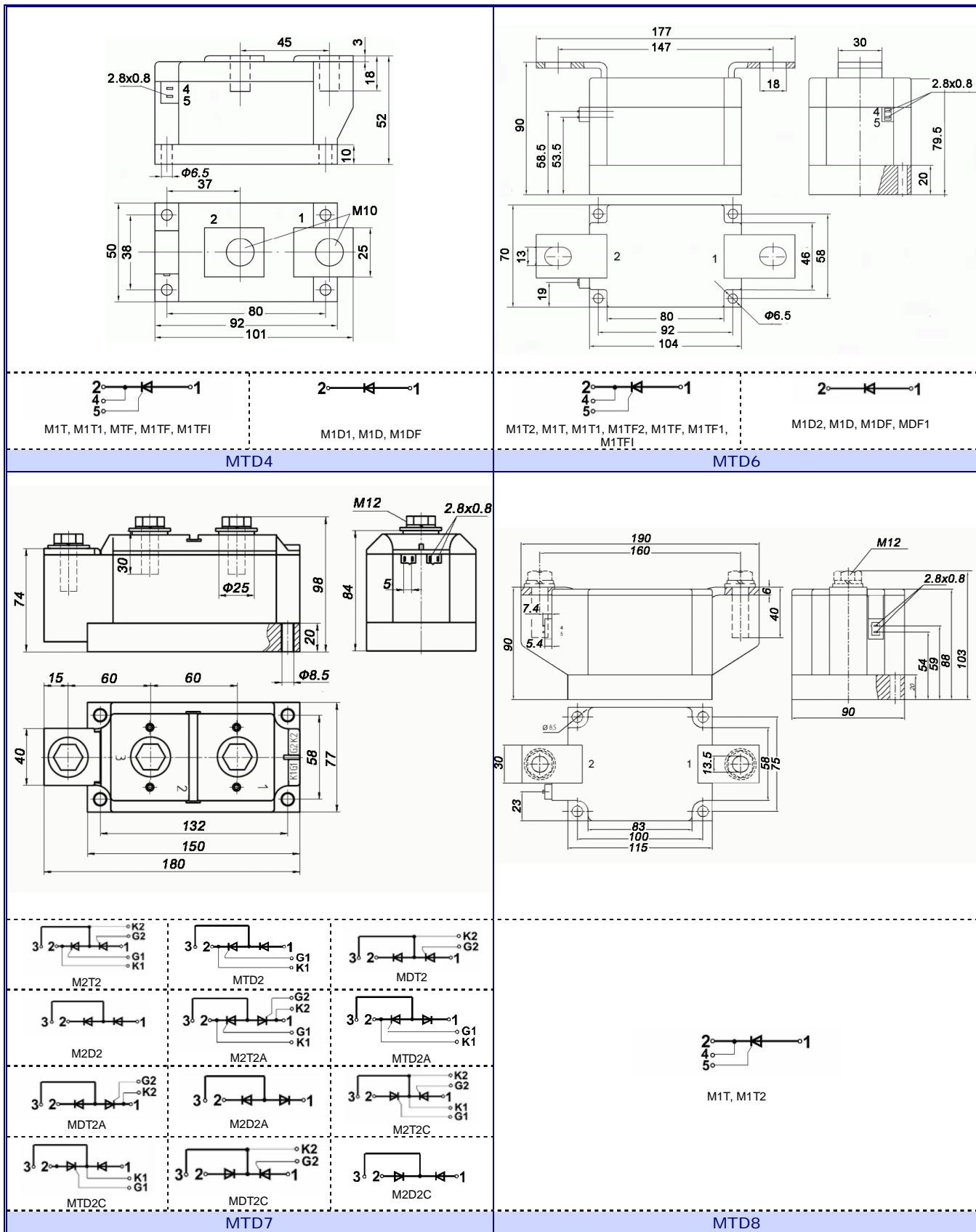
Type	$V_{DRM}$ , $V_{RRM}$ V	$I_{T(AV)}$ ( $T_C$ , °C) A	$I_{TSM}$ 10ms kA	$V_{T(TO)}$ V	$r_T$ mΩ	$(di_T/dt)_{cr}$ A/μs	$(dv_D/dt)_{cr}$ V/μs	$t_q$ μs	$R_{th(j-c)}$ °C/W	$T_{VJM}$ °C	$V_{isol}$ V	Case	
M2TFI-100 ----- M2TFIA-100	600-1200	100(80)	2.5	1.38	2.70	800	1000	16-63	0.210	125	2500	 MTD2 w =500g	
M2TFI-125 ----- M2TFI-160 ----- M2TFIA-160	600-1400	125(80)	4.0	-	-	1000	1000	25-63	0.230	125	3000	 MTD3 w =800g	
M2TFI-160 ----- M2TFIA-160	1500-2000	160(85)	6.0	1.25	1.30	1000	1000	32-63	0.130	125	3000		
M2TFI-200 ----- M2TFIA-200	300-900	200(80)	7.0	1.20	0.80	1000	1000	12-63	0.130	125	3000		
M1TFI-320 ----- M1TFI-320 ----- M1TFI-400	600-1400	320(85)	9.0	1.20	0.64	1000	1000	25-63	0.073	125	3000		 MTD4 w =900g
M1TFI-320 ----- M1TFI-400	1500-2000	320(85)	7.5	1.25	0.70	1000	1000	40-63	0.073	125	3000		
M1TFI-400	300-900	400(80)	6.3	1.20	0.45	1000	1000	12-63	0.073	130	3000		
M2TFI-320 ----- M2TFIA-320 ----- M2TFI-320 ----- M2TFIA-320 ----- M2TFI-400 ----- M2TFIA00	600-1400	320(85)	9.0	1.20	0.64	1000	1000	25-63	0.073	125	3000	 MTD5 w =1500g	
M2TFI-320 ----- M2TFIA-320	1500-2000	320(83)	7.5	1.25	0.70	1000	1000	40-63	0.073	125	3000		
M2TFI-400 ----- M2TFIA00	300-900	400(80)	6.3	1.20	0.45	1000	1000	12-63	0.073	125	3000		
M1TFI-500 ----- M1TFI2-500 ----- M1TFI-630	600-1400	500(80)	17	1.30	0.24	1000	1000	25-63	0.042	125	3000		 MTD6 w =2300g
M1TFI2-500 ----- M1TFI-630	1500-2000	500(80)	16	1.34	0.34	1000	1000	32-63	0.042	125	3000		
M1TFI-630	300-900	630(80)	18	1.20	0.34	1000	1000	12-40	0.042	125	3000		
M1TFI-630	300-900	630(80)	18	1.20	0.34	1000	1000	12-40	0.042	125	3000		

## FAST SWITCHING THYRISTOR-DIODE MODULES

Type	$V_{DRM}$ , $V_{RRM}$ V	$I_{T(AV)}$ ( $T_C$ , °C) A	$I_{TSM}$ 10ms kA	$V_{T(TO)}$ V	$r_T$ mΩ	$(di_T/dt)_{cr}$ A/μs	$(dv_D/dt)_{cr}$ V/μs	$t_q$ μs	$t_{rr}$ μs	$R_{th(j-c)}$ °C/W	$T_{VJM}$ °C	$V_{isol}$ V	Case
MTFIDF-100 ----- MDFTFI-100	600 -1200	100(80)	2.5	1.38	2.70	800	1000	16-63	2.5-4	0.210	125	2500	 MTD2 w =500g
MTFIDF-160 ----- MDFTFI-160 ----- MTFIDF-160 ----- MDFTFI-160	600 -1400	160(85)	4.0	1.35	1.10	1000	1000	16-63	2.5-4	0.130	125	3000	 MTD3 w =800g
MTFIDF-160 ----- MDFTFI-160	1500 -2000	160(85)	6.0	1.25	1.30	1000	1000	32-63	3.2-4	0.130	125	3000	
MTFIDF-200 ----- MDFTFI-200	300 -900	200(80)	7.0	1.20	0.80	1000	1000	12-63	2.5-4	0.130	125	3000	
MTFIDF-320 ----- MDFTFI-320 ----- MTFIDF-320 ----- MDFTFI-320	600 -1400	320(85)	9.0	1.20	0.64	1000	1000	25-63	2.5-5	0.073	125	3000	
MTFIDF-320 ----- MDFTFI-320	1500 -2000	320(83)	7.5	1.25	0.70	1000	1000	40-63	3.2-5	0.073	125	3000	
MTFIDF-400 ----- MDFTFI-400	300 -900	400(80)	6.3	1.20	0.45	1000	1000	12-63	2.5-5	0.073	130	3000	
MTFIDF-400 ----- MDFTFI-400	300 -900	400(80)	6.3	1.20	0.45	1000	1000	12-63	2.5-5	0.073	130	3000	



# OUTLINES



## SINGLE-PHASE AND THREE-PHASE DIODE-THYRISTOR BRIDGES

### Features:

- Plastic case with screw fastening of busbars
- Internal DBC insulation ( $Al_2O_3$ )
- Easy mounting

### Applications:

- Single and three-phase bridges for power supplies
- Input rectifiers for frequency converters
- Rectifiers for DC motor excitation windings
- Battery charging rectifiers



Type	$V_{RRM}$	$I_D$ $T_c=100^\circ C$	$I_{FSM}$ $T=150^\circ C$	$V_{FM}/I_{FM}$	$V_{TO}$ $T=150^\circ C$	$r_T$ $T=150^\circ C$	$R_{th(j-c)}$	$T_{VJM}$	$V_{isol}$	Case
	V	A	A	V/A	V	m $\Omega$	$^\circ C/W$	$^\circ C$	V	
<b>Single-phase diode bridges</b>										
M4D-63	400-1600	63	1200	1.50/170	0.93	3.4	0.400	150	3000	MMD1 w =180g
M4D-80	400-1600	80	1300	1.35/170	0.93	2.4	0.300	150	3000	
M4D-200	400-1600	200	2000	1.45/300	0.90	1.7	0.250	150	3000	MI4-2 w =400g
<b>Three-phase diode bridges</b>										
M6D-63	400-1600	63	1000	1.70/170	0.93	4.5	0.500	150	3000	MMD1 w =180g
M6D-80	400-1600	80	1200	1.50/170	0.93	3.4	0.400	150	3000	
M6D-100	400-1600	100	1300	1.35/170	0.93	2.4	0.300	150	3000	MI4-2 w =400g
M6D-250	400-1600	250	2000	1.45/300	0.90	1.7	0.250	150	3000	

Type	$V_{RRM}, V_{DRM}$	$I_D$ $T_c=85^\circ C$	$I_{FSM}, I_{TSM}$ $T=125^\circ C$	$V_{FM}, V_{TM}$ $I_F=250A$	$V_{T(TO)}$ $T=125^\circ C$	$r_T$ $T=125^\circ C$	$(dv_T/dt)_{cr}$	$R_{th(j-c)}$	$T_{VJM}$	$V_{isol}$	Case
	V	A	A	V	V	m $\Omega$	V	$^\circ C/W$	$^\circ C$	V	
<b>Single-phase diode-thyristor bridges</b>											
M4TD-160	400-1600	160	1500	1.65	0.93	3.3	200-1000	0.3	125	3000	MI4-2 w =400g
<b>Three-phase diode-thyristor bridges</b>											
M6TD-160	400-1600	170	1300	1.85	0.95	4.1	200-1000	0.4	125	3000	MI4-2 w =400g
M6TD-200	400-1600	200	1500	1.65	0.93	3.3	200-1000	0.3	125	3000	

Type	$V_{DRM}, V_{RRM}$	$I_D$ $T_c=85^\circ C$	$I_{TSM}$ $T=125^\circ C$	$V_{TM}$ $I_F=250A$	$V_{T(TO)}$ $T=125^\circ C$	$r_T$ $T=125^\circ C$	$(dv_T/dt)_{cr}$	$R_{th(j-c)}$	$T_{VJM}$	$V_{isol}$	Case
	V	A	A	V	V	m $\Omega$	V	$^\circ C/W$	$^\circ C$	V	
<b>Single-phase thyristor bridges</b>											
M4T-160	400-1600	160	1500	1.65	0.93	3.3	200-1000	0.3	125	3000	MI4-2 w =400g
<b>Three-phase thyristor bridges</b>											
M6T-160	400-1600	170	1300	1.85	0.95	4.1	200-1000	0.4	125	3000	MI4-2 w =400g
M6T-200	400-1600	200	1500	1.65	0.93	3.3	200-1000	0.3	125	3000	

# OUTLINES

<p>MMD1 w =180g</p>		
<p>MI4-2 w =400g</p>		
<p>MI4-2 w =400g</p>		